## $2 \times 6 \mathrm{~W}$ CAR RADIO AMPLIFIER PLUS SOLID STATE SWITCH

- OUTPUT POWER $2 x 6 \mathrm{~W} / 4 \Omega$ @14.4V, 1 KHz , 10\%
- SOLID STATE POWER SWITCH INCLUDED ( $1 \mathrm{~A} @$ VDrop $=0.8 \mathrm{~V}$ Typ.)
- MINIMUM EXTERNAL COMPONENT COUNT
- INTERNALLY FIXED GAIN (40dB)
- NO BOOTSTRAP CAPACITORS
- NO EXTERNAL COMPENSATION
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
- NO AUDIBLE POP DURING MUTE/ST-BY OPERATIONS
- LOW SUPPLY SELF MUTING


## PROTECTIONS

- AC AUDIO OUTPUTS SHORT CIRCUIT TO GND
- DC AUDIO OUTPUTS SHORT CIRCUIT TO GND AND TO Vs AT POWER ON
- SWITCH OUTPUT INTERNAL CURRENT LIMITATION
- OVERRATING CHIP TEMPERATURE WITH SOFT THERMAL LIMITER
- LOAD DUMP
- FORTUITOUS OPEN GND

- REVERSE BATTERY
- ESD


## DESCRIPTION

The TDA7365 is a new technology Dual Audio Amplifier in Multiwatt15 package especially designed for stereo car radio applications.
Thanks to the fully complementary output configuration the TDA7365 delivers a rail to rail voltage swing with no need of boostrap capacitors It includes a solid state switch, enabled by a ST-BY function common to the audio section, suitable for supplying both the signal processing part of the car radio set and the lamps. As a results the power-on operation is simplified, thereby saving cost and space in the whole power section.

## BLOCK DIAGRAM



PIN CONNECTION (Top view)


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{S}}$ | DC Supply Voltage | 28 | V |
| $\mathrm{~V}_{\mathrm{OP}}$ | Operating Supply Voltage | 18 | V |
| $\mathrm{~V}_{\text {PEAK }}$ | Peak Supply Voltage ( $\mathrm{t}=50 \mathrm{~ms}$ ) | 40 | V |
| $\mathrm{I}_{\mathrm{O}}$ | Audio Channels Output Peak Current (not rep. $\mathrm{t}=100 \mu \mathrm{~s}$ ) | 4 | A |
| $\mathrm{I}_{\mathrm{O}}$ | Audio Channels Output Peak Current (rep. $\mathrm{f}>10 \mathrm{~Hz}$ ) | 3 | A |
| $\mathrm{I}_{\mathrm{O}}$ | Switch Output Peak Current | (internally limited) 1.5 | A |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation ( $\mathrm{T}_{\text {case }}=85^{\circ} \mathrm{C}$ ) | 32 | W |
| $\mathrm{~T}_{\text {stg }}, \mathrm{T}_{\mathrm{j}}$ | Storage and Junction Temperature | -40 to 150 | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| Symbol | Description | Value | Unit |  |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{R}_{\text {th } \mathrm{j} \text {-case }}$ | Thermal Resistance Junction-case | Max | 2 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

ELECTRICAL CHARACTERISTICS (Refer to the test circuit; $\mathrm{V}_{\mathrm{S}}=14.4 \mathrm{~V} ; \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, $\mathrm{f}=1 \mathrm{kHz}$, unless otherwise specified)

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Vs | Supply Range |  | 8 |  | 18 | V |
| $\mathrm{I}_{\mathrm{d}}$ | Total Quiescent Drain Current | Power Switch Unloaded |  | 80 |  | mA |
| Po | Output Power | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=4 \Omega ; \mathrm{THD}=10 \% \\ & \text { each channel } \\ & \hline \end{aligned}$ | 5.5 | 6 |  | W |
|  |  | $\mathrm{R}_{\mathrm{L}}=2 \Omega ; \mathrm{THD}=10 \%$ each channel |  | 9 |  | W |
| d | Distortion | $\mathrm{P}_{\mathrm{O}}=0.1$ to 3 W |  | 0.08 | 0.3 | \% |
| CT | Cross Talk | $\begin{aligned} & \mathrm{f}=1 \mathrm{kHz} ; \mathrm{R}_{\mathrm{g}}=0 \\ & \mathrm{f}=10 \mathrm{kHz} ; \mathrm{R}_{\mathrm{g}}=0 \end{aligned}$ | 50 | $\begin{aligned} & 55 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| RIN | Input Impedance |  | 40 | 50 |  | $\mathrm{K} \Omega$ |
| $\mathrm{G}_{V}$ | Voltage Gain |  | 39 | 40 | 41 | dB |
| Gv | Voltage Gain Match. |  |  |  | 1 | dB |
| EIN | Input Noise Voltage (*) | $\mathrm{Rg}=0$ |  | 1.2 | 5 | $\mu \mathrm{V}$ |
| SVR | Supply Voltage Rejection | $\begin{aligned} & \mathrm{R}_{\mathrm{g}}=0 ; \mathrm{f}=100 \mathrm{~Hz} ; \\ & \mathrm{V}_{\mathrm{r}}=0.5 \mathrm{~V}_{\mathrm{ms}} \end{aligned}$ | 45 | 50 |  | dB |
| ASB | Stand-by Attenuation |  | 60 | 90 |  | dB |
| ISB | ST-BY Current Consumption |  |  |  | 100 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {SB IN }}$ | ST-BY IN Threshold Voltage |  |  |  | 1.5 | V |
| $\mathrm{V}_{\text {SB OUT }}$ | ST-BY OUT Threshold Voltage |  | 3.5 |  |  | V |
| $\mathrm{V}_{\mathrm{MIN}}$ | MUTE IN Threshold Voltage |  |  |  | 1.5 | V |
| VM OUT | MUTE OUT Threshold Voltage |  | 3.5 |  |  | V |

## POWER SWITCH CHARACTERISTICS

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{Op}}$ | Continuous Output Current |  |  | 1.2 |  | A |
| $\mathrm{~V}_{\mathrm{DROP}}$ | Dropout Voltage | $\mathrm{IO}=1 \mathrm{~A}$ |  |  | 1.4 | V |

(*) 22 Hz to 22 KHz
(**) A weighted

## TEST AND APPLICATION CIRCUIT



Figure 1: P.C.Board and component layout of the Test and Application Circuit 1:1 scale.


Figure 2: Quiescent Drain Current vs. Supply Voltage


Figure 4: Output Power vs. Supply Voltage


Figure 3: Output Power vs. Supply Voltage


Figure 5: Distortion vs. Output Power


Fiigure 6: Distortion vs. Frequency


Fiigure 8: Cross-Talk vs. Frequency


Figure 10: Total Power Dissipation and Efficiency vs. Output Power


Figure 7: Supply Voltage Rejection


Figure 9: Switch Drop-out vs. Switch Current


Figure 11: Total Power Dissipation and Efficiency


| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 5 |  |  | 0.197 |
| B |  |  | 2.65 |  |  | 0.104 |
| C |  |  | 1.6 |  |  | 0.063 |
| D |  | 1 |  |  | 0.039 |  |
| E | 0.49 |  | 0.55 | 0.019 |  | 0.022 |
| F | 0.66 |  | 0.75 | 0.026 |  | 0.030 |
| G | 1.02 | 1.27 | 1.52 | 0.040 | 0.050 | 0.060 |
| G1 | 17.53 | 17.78 | 18.03 | 0.690 | 0.700 | 0.710 |
| H1 | 19.6 |  |  | 0.772 |  |  |
| H2 |  |  | 20.2 |  |  | 0.795 |
| L | 21.9 | 22.2 | 22.5 | 0.862 | 0.874 | 0.886 |
| L1 | 21.7 | 22.1 | 22.5 | 0.854 | 0.870 | 0.886 |
| L2 | 17.65 |  | 18.1 | 0.695 |  | 0.713 |
| L3 | 17.25 | 17.5 | 17.75 | 0.679 | 0.689 | 0.699 |
| L4 | 10.3 | 10.7 | 10.9 | 0.406 | 0.421 | 0.429 |
| L7 | 2.65 |  | 2.9 | 0.104 |  | 0.114 |
| M | 4.25 | 4.55 | 4.85 | 0.167 | 0.179 | 0.191 |
| M1 | 4.63 | 5.08 | 5.53 | 0.182 | 0.200 | 0.218 |
| S | 1.9 |  | 2.6 | 0.075 |  | 0.102 |
| S1 | 1.9 |  | 2.6 | 0.075 |  | 0.102 |
| Dia1 | 3.65 |  | 3.85 | 0.144 |  | 0.152 |
|  |  |  |  |  |  |  |



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